

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_J = 25^\circ\text{C}$. $V_{DD33} = 3.3\text{V}$, $V_{IN_SNS} = 12\text{V}$, V_{DD25} and REF pins floating, unless otherwise indicated. (Notes 2, 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
f_{IN_ADC}	Input Sampling Frequency			62.5		kHz
I_{IN_ADC}	Input Leakage Current	$V_{IN_ADC} = 0\text{V}$, $0\text{V} \leq V_{COMMONMODE} \leq 6\text{V}$, Current Sense Mode	●		± 0.5	μA
	Differential Input Current	$V_{IN_ADC} = 0.17\text{V}$, Current Sense Mode	●	80	250	nA
		$V_{IN_ADC} = 6\text{V}$, Voltage Sense Mode	●	10	15	μA

DAC Output Characteristics

N_VDACP	Resolution	1.29				10	Bits	
VFS_VDACP	Full-Scale Output Voltage (Programmable)	DAC Code = 0x3FF	Buffer Gain Setting_0	●	1.32	1.38	1.44	V
		DAC Polarity = 1	Buffer Gain Setting_1	●	2.53	2.65	2.77	V
INL_VDACP	Integral Nonlinearity	(Note 8)	✗		2.48		±2	LSB
DNL_VDACP	Differential Nonlinearity	(Note 8)	●				±2.4	LSB
VOS_VDACP	Offset Voltage	(Note 8)	●				±20	mV
VDACP	Load Regulation (VDACPn – VDACMn)	VDACPn = 2.65V, IVDACPn Sourcing = 2mA			100			ppm/mA
		VDACPn = 0.1V, IVDACPn Sinking = 2mA			100			ppm/mA
	PSRR (VDACPn – VDACMn)	DC: 3.13V ≤ VDD33 ≤ 3.47V			60			dB
		100mV Step in 20ns with 50pF Load			40			dB
	DC CMRR (VDACPn – VDACMn)	–0.1V ≤ VDACMn ≤ 0.1V			60			dB
	Leakage Current	VDACPn Hi-Z, 0V ≤ VDACPn ≤ 6V	●				±100	nA
	Short-Circuit Current Low	VDACPn Shorted to GND	●	–10		–4		mA
	Short-Circuit Current High	VDACPn Shorted to VDD33	●	4		10		mA
COUT	Output Capacitance	VDACPn Hi-Z			10			pF
ts_VDACP	DAC Output Update Rate	Fast Servo Mode			500			μs

DAC Soft-Connect Comparator Characteristics

V_{OS_CMP}	Offset Voltage	$V_{DACPn} = 0.2\text{V}$	●	± 1	± 18	mV
		$V_{DACPn} = 1.3\text{V}$	●	± 2	± 26	mV
		$V_{DACPn} = 2.65\text{V}$	●	± 3	± 52	mV

Voltage Supervisor Characteristics

V_{IN_VS}	Input Voltage Range (Programmable)	$V_{IN_VS} = (V_{SENSEPN} - V_{SENSEMN})$	Low Resolution Mode	●	0	6	V
			High Resolution Mode	●	0	3.8	V
		Single-Ended Voltage: $V_{SENSEMN}$		●	-0.1	0.1	V
N_VS	Voltage Sensing Resolution	0V to 3.8V Range: High Resolution Mode			4		mV/LSB
		0V to 6V Range: Low Resolution Mode			8		mV/LSB
TUE_VS	Total Unadjusted Error	$2\text{V} \leq V_{IN_VS} \leq 6\text{V}$, Low Resolution Mode	●			± 1.25	% of Reading
		$1.5\text{V} < V_{IN_VS} \leq 3.8\text{V}$, High Resolution Mode	●			± 1.0	% of Reading
		$0.8\text{V} \leq V_{IN_VS} \leq 1.5\text{V}$, High Resolution Mode	●			± 1.5	% of Reading
t_{S_VS}	Update Period				12.21		μs